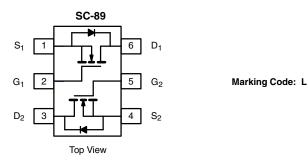




N-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (mA)	
20	5 at V _{GS} = 4.5 V	200	
	7 at V _{GS} = 2.5 V	175	
	9 at V _{GS} = 1.8 V	150	
	10 at V _{GS} = 1.5 V	50	



Ordering Information: Si1034X-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET: 1.5 V Rated
- Low-Side Switching
- Low On-Resistance: 5 Ω
- Low Threshold: 0.9 V (typ.)
- Fast Switching Speed: 35 ns (typ.)
- 1.5 V Operation
- Gate-Source ESD Protected: 2000 V
 Compliant to RoHS Directive 2002/95/EC

BENEFITS

- · Ease in Driving Switches
- · Low Offset (Error) Voltage
- · Low-Voltage Operation
- · High-Speed Circuits
- Low Battery Voltage Operation

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- · Battery Operated Systems
- · Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers

ABSOLUTE MAXIMUM RATINGS	$T_A = 25$ C, unle	SS Officialise	noteu)		
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	20		V
Gate-Source Voltage		V _{GS}	± 5		V
Continuous Dunin Courset /T 150 90\8	T _A = 25 °C	I _D	190	180	A
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		140	130	
Pulsed Drain Current ^b		I _{DM}	650		mA
Continuous Source Current (Diode Conduction)		Is	450	380	
N	T _A = 25 °C	P _D	280	250	mW
Maximum Power Dissipation ^a	T _A = 85 °C		145	130	
Operating Junction and Storage Temperature Range	је	T _J , T _{stg}	- 55 to 150		°C
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000		V

Notes

- a. Surface mounted on FR4 board.
- b. Pulse width limited by maximum junction temperature.

Pb-free RoHS OMPLIANT

COMPLIANT HALOGEN FREE

Vishay Siliconix



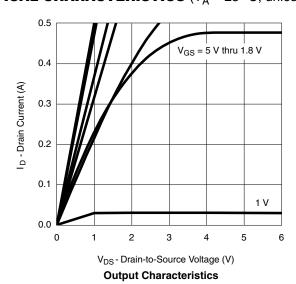
SPECIFICATIONS (T _A = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.40		1.2	V	
Gate-Body Leakage	Lear	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 2.8 \text{ V}$		± 0.5	± 1.0	μА	
Gale-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$		± 1.0	± 3.0		
Zara Oata Wallana Busin Oamant	I _{DSS}	V _{DS} = 16 V, V _{GS} = 0 V		1	500	nA	
Zero Gate Voltage Drain Current	DSS	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	250			mA	
Drain-Source On-State Resistance ^a		$V_{GS} = 4.5 \text{ V}, I_D = 200 \text{ mA}$			5	Ω	
	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 175 \text{ mA}$			7		
		$V_{GS} = 1.8 \text{ V}, I_D = 150 \text{ mA}$			9		
		$V_{DS} = 1.5 \text{ V}, I_D = 40 \text{ mA}$			10		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 200 mA		0.5		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 150 mA, V _{GS} = 0 V			1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			750			
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 150 \text{ mA}$		75		рC	
Gate-Drain Charge	Q_{gd}			225			
Turn-On Delay Time	t _{d(on)}				50		
Rise Time	t _r	V_{DD} = 10 V, R_L = 47 Ω			25	ns	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong \text{200 mA}, \text{V}_\text{GEN}=\text{4.5 V}, \text{R}_\text{g}=\text{10 }\Omega$			50	115	
Fall Time	t _f				25		

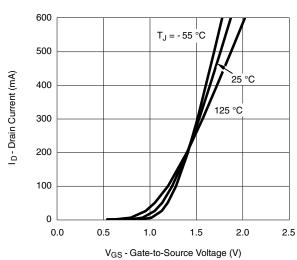
Notes:

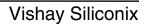
- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

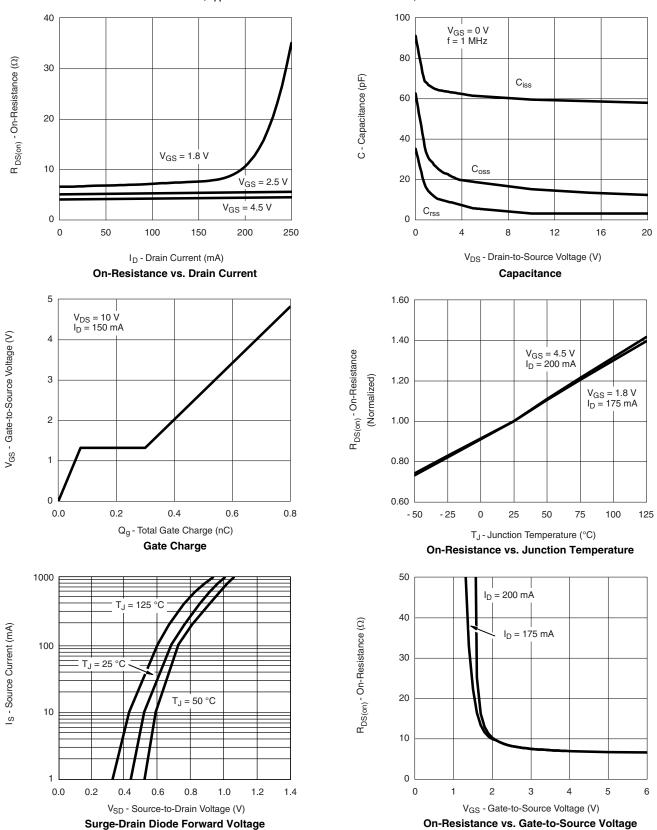








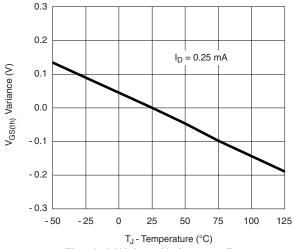
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)

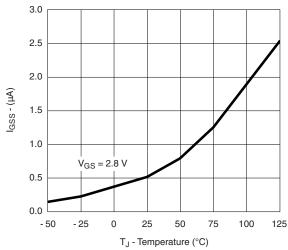


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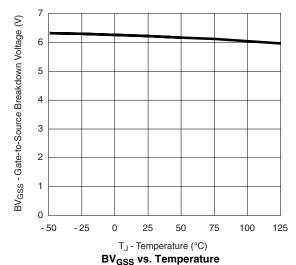
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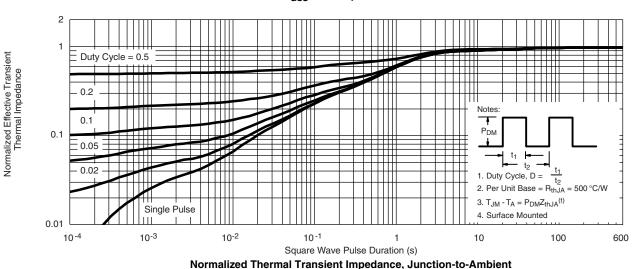




Threshold Voltage Variance vs. Temperature





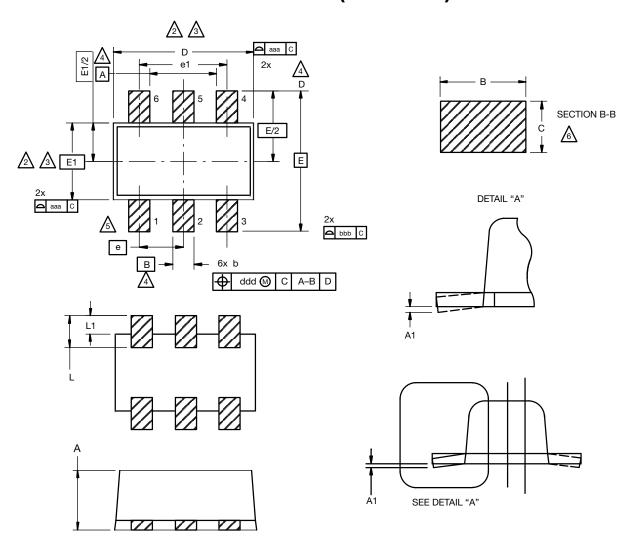


Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon

Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71427.



SC-89 6-Leads (SOT-563F)



Notes

1. Dimensions in millimeters.

Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.

Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

ADatums A, B and D to be determined 0.10 mm from the lead tip.

 Δ Terminal numbers are shown for reference only.

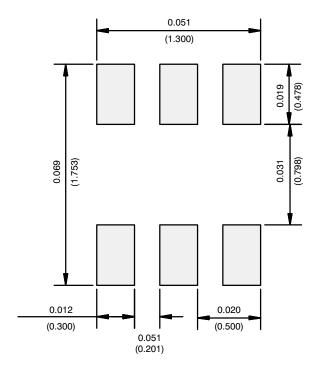
These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

DIM.	MILLIMETERS				
DIIVI.	MIN.	. NOM.	MAX.		
Α	0.56	0.58	0.60		
A1	0	0.02	0.10		
b	0.15	0.22	0.30		
С	0.10	0.14	0.18		
D	1.50	1.60	1.70		
E	1.50	1.60	1.70		
E1	1.15	1.20	1.25		
е	0.45	0.50	0.55		
e1	0.95	1.00	1.05		
L	0.25	0.35	0.50		
L1	0.10	0.20	0.30		
C14-0439-Rev. C, 11-Aug-14 DWG: 5880					

Revision: 11-Aug-14 1 Document Number: 71612



RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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